

Imaging of vortex configurations in thin films by scanning-tunneling microscopy

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We report on imaging of vortices in thin superconducting films using surface passivation with an ultrathin Au layer. This allows investigation of surfaces that oxidize easily, as well as the mounting of samples in air. We studied vortex configurations in a material with weak vortex pinning (*a*-Mo_{2.7}Ge) and a strongly pinning material (NbN) at 4.2 K in magnetic fields up to 1.4 T. In *a*-Mo_{2.7}Ge, we observe a well-ordered hexagonal lattice, with local defects beginning to appear around 1.0 T. In NbN, the vortex lattice is fully disordered. © 2003 American Institute of Physics. [DOI: 10.1063/1.1554481]

Scanning tunneling microscopy (STM) is a useful technique for imaging vortex structures in superconductors. One of the principal advantages in comparison with other imaging tools, such as magneto-optics, Bitter decoration, or magnetic force microscopy, is that STM measures the electronic density of states instead of the magnetic flux density, thus being sensitive on the scale of the superconducting coherence length ξ , rather than the magnetic penetration depth λ . This opens a much larger magnetic field region for investigations, in particular the field region where the vortex-vortex spacing is smaller than λ . However, due to the requirements of having a clean, almost atomically flat surface, vortices have been observed by STM mainly in four different single-crystalline materials: NbSe₂,¹ YBa₂Cu₃O_{7- δ} ,² Bi₂Sr₂CaCu₂O_{8+ δ} ,³ and (Lu/Y)Ni₂B₂C,^{4,5} while in thin films we know of only one report on observing vortex signatures.⁶

In this letter, we report on the result of a passivation technique to overcome such major obstacles as surface roughness and oxidation, which make tunneling and scanning impossible. We use it to investigate the vortex structures in two different superconductors, *a*-Mo_{2.7}Ge (= amorphous Mo₇₀Ge₃₀) and NbN, at 4.2 K and up to $B = 1.4$ T. Both materials can be prepared in thin film form; *a*-Mo_{2.7}Ge has a superconducting transition temperature T_c of 6.5 K and an upper critical field B_{c2} at 4.2 K of 6 T. In addition, it shows moderate intrinsic pinning strength, basically due to the absence of grain boundaries; for a typical film thickness of 50 nm at intermediate fields and low temperatures, the critical current density J_c for onset of vortex motion is of the order of 10^6 A/m².⁷ In strongly pinning NbN with a T_c of 11 K and a B_{c2} at 4.2 K of about 8.8 T, J_c is at least two orders of magnitude higher.⁸

For amorphous films, spectroscopic imaging is feasible because of the very flat surface characteristics. However, even a small amount of oxidation is detrimental to mapping

the superconducting gap, which is the way to determine vortex core positions. To prevent this, we cap the amorphous film with a very thin Au film. It turns out that sputtering even 3 nm of Au on *a*-Mo_{2.7}Ge is enough to form a closed layer, which still allows one to perform gap spectroscopy due to the proximity effect. For crystalline films such as NbN, oxidation also has to be prevented, but here, a capping Au layer does not close so easily. For a 50-nm NbN layer, passivation by a Au layer is possible,⁹ but better results are obtained by depositing a thin layer (20 nm) of *a*-Mo_{2.7}Ge followed by the Au capping layer. This results in a flatter surface than when Au is directly deposited on NbN, and it has a more uniform thickness, which is an advantage for the proximity effect. The important point to realize is that the vortex positions as measured on the Au surface are still dictated by the pinning of the vortices in the NbN layer, since the pinning by the *a*-Mo_{2.7}Ge layer is much too weak to influence the vortex configuration.

The 50-nm-thick *a*-Mo_{2.7}Ge films were rf sputtered from a composite Mo/Ge target at room temperature in an Ar atmosphere on a Si substrate. Atomic force microscopy (AFM) on such a film showed a flat surface over the scan range of 0.5 μ m within the resolution of our AFM measurement (0.4 nm). Next, we deposited the Au capping layer immediately after depositing the *a*-Mo_{2.7}Ge by first sputtering about 3-nm Au in Ar (100%) atmosphere to obtain a closed Au layer, followed by another 3 nm in Ar/O₂ (95%/5% partial pressure) to obtain a flat Au surface consisting of small grains. Highest resolution is achieved having Au grains as small as possible, which is promoted by the O₂ addition. The 50-nm-thick NbN samples were reactively rf-sputtered at room temperature from a Nb target in an Ar/N₂ atmosphere (95%/5% partial pressure). This was followed by a 20-nm layer of *a*-Mo_{2.7}Ge and a Au layer as for the *a*-Mo_{2.7}Ge films. After sputtering, the samples were taken out of the vacuum and mounted on the scanner of the STM. During this procedure, which takes about half an hour, the samples were exposed to air.

Examples of the topography as measured by STM can be found in Refs. 9 and 10. The surface shows grains with a size of 10 nm and a maximum height variation of 1 nm over a scan length of 400 nm. The STM measurements were per-

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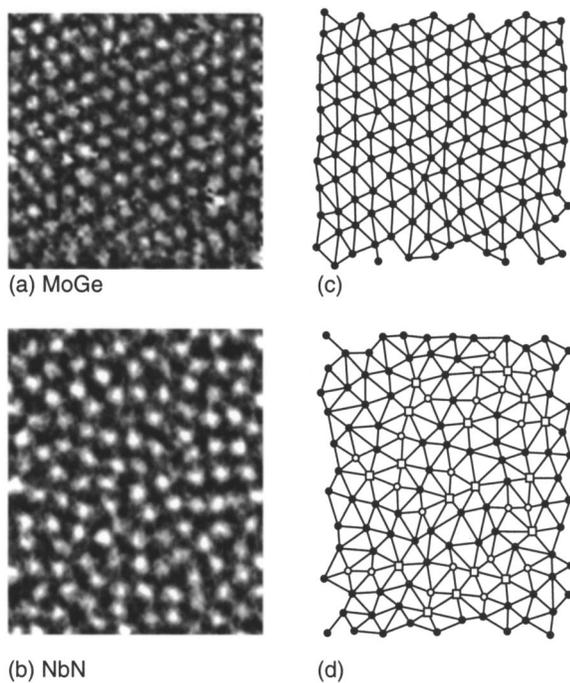


FIG. 1. Vortex configurations as measured in a - $\text{Mo}_{2.7}\text{Ge}$ and NbN at 4.2 K and magnetic fields of 0.5 and 0.8 T, respectively. Scan ranges are $704 \times 704 \text{ nm}^2$ and $510 \times 680 \text{ nm}^2$, respectively. On the right, the corresponding triangulations are shown. Black circles correspond to vortices with coordination number $z=6$, open circles have $z<6$, while the open squares mark vortices with $z>6$.

formed in the same setup as mentioned in Ref. 11, and the STM itself is directly immersed in the liquid helium; all data shown are acquired at 4.2 K.

The vortex imaging is done by acquiring full I - V tunneling spectra simultaneously with the topography measurement (constant current mode): at each point, after stabilizing the tip height, the feedback is switched off and an I - V curve is measured. From these I - V curves, we evaluate the ratio of the zero-bias and high-bias (larger than the superconducting gap energy Δ) slopes, providing information about the proximity-induced, local quasiparticle density of states, $N_{S'}(E, r)$, where E is the energy of the quasiparticles and r is the position of the tip on the sample. On choosing a resolution of 128×128 points per image the acquisition time is about 1 h. For all vortex images shown, except otherwise mentioned, we applied some basic image processing to the images (smoothing and balancing gray scale).

In Figs. 1(a) and 1(b) we show results obtained on a - $\text{Mo}_{2.7}\text{Ge}$ in a field of 0.5 T and on NbN in a field of 0.8 T, which corresponds to the same reduced field $b=B/B_{c2}=0.09$ for both samples. These results demonstrate that we are able to clearly image vortex structures on both films. The vortex cores are mostly well defined, although there is variation in the brightness both within the core and comparing different cores. This is due mainly to the grain structure of the Au layer: $N_{S'}(E, r)$ is constant in a grain,¹² but can vary due to inelastic scattering at grain boundaries. The scan range is chosen such that, for both samples, around 130 vortices are imaged. The vortex density d of $258 \pm 20 \mu\text{m}^{-2}$ (a - $\text{Mo}_{2.7}\text{Ge}$) and $389 \pm 20 \mu\text{m}^{-2}$ (NbN) corresponds well to the expected value, $d=B/\Phi_0=242$ and $385 \mu\text{m}^{-2}$, respectively (with Φ_0 the flux quantum).

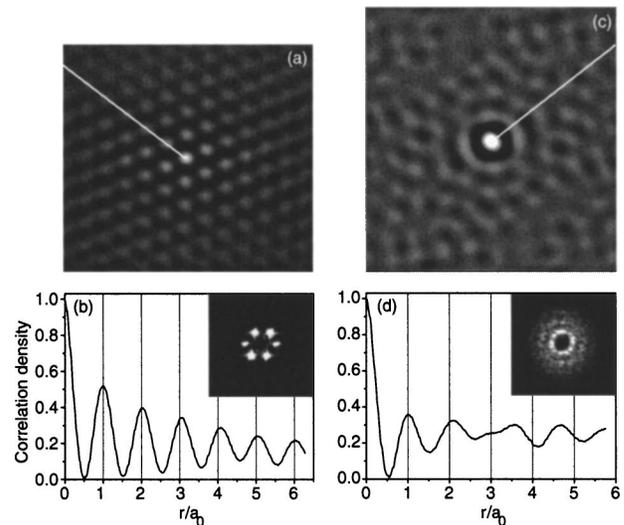


FIG. 2. Autocorrelation data (a and c) of the images shown in Fig. 1. Panels b and d show a cross section along the white lines in panels a and c. The horizontal axis is in units of the vortex-vortex distance a_0 . The insets show the 2D Fourier transforms.

The vortex lattice (VL) configuration in both films is quite different. A quick way to demonstrate this is to perform a triangulation analysis to find the number of nearest neighbors for each vortex, which should be six for the perfect triangular lattice. The triangulation results given in Figs. 1(c) and 1(d) show that the VL in a - $\text{Mo}_{2.7}\text{Ge}$ is without any defects, while in the case of NbN, a large number of vortices (36%) has five- or sevenfold coordination.

For a more quantitative analysis of the correlation of vortex positions, we generated two-dimensional (2D) maps of the autocorrelation function (with distances r now scaled on a_0 , the vortex-vortex distance defined from the peaks in the autocorrelation graphs), shown in Fig. 2. These maps directly yield an estimate for the VL correlation length R_c , in contrast to the often-presented 2D Fourier transforms [shown in the insert of Figs. 2(b) and 2(d)] where this information is in the width of the peaks. From the pictures, it is evident that in a - $\text{Mo}_{2.7}\text{Ge}$ the VL has both high translational (bond length) and rotational (bond orientation) correlation, with a lower bound of $R_c \approx 6 a_0$ set by the limited amount of vortices. For NbN, we find $R_c \approx 1.5 a_0$ and almost no orientational correlation. The gray features that still can be seen in Fig. 2(c), the small variations of correlation above $2r/a_0$, and the nonuniformity of the ring in the Fourier transform in Fig. 2(d) are due to the limited amount of vortices on which to do these statistics.

Next, we consider the field dependence of the correlations. No qualitative changes were found in the VL structure of the NbN films up to 1.4 T, the highest magnetic field measured. In the whole field regime, we therefore essentially find $R_c \approx (1-2)a_0$. This confirms on a local scale the conclusion from pinning force measurements, that in the field regime below $b \approx 0.15$, grain boundary pinning is more important than the elastic interactions between vortices, leading to isolated vortex behavior.¹³ For a - $\text{Mo}_{2.7}\text{Ge}$, we show additional data of measurements at 0.07, 0.3, and 1.0 T in Fig. 3. In the lowest fields, we have the problem that the scan range, and therefore the total amount of vortices that can be imaged, is limited. However, inspection of Fig. 3(a) reveals several

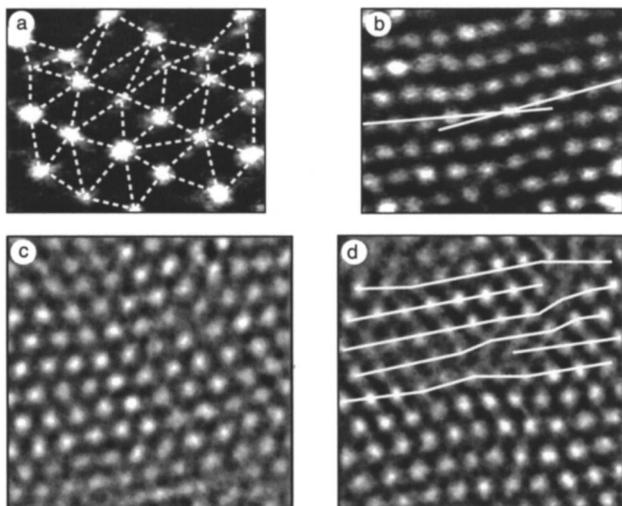


FIG. 3. Images of $a\text{-Mo}_{2.7}\text{Ge}$ vortex lattices for various flux densities. Magnetic field and scan size are respectively: (a) 0.07 T, $700 \times 858 \text{ nm}^2$, (b) 0.3 T, $700 \times 858 \text{ nm}^2$, (c) and (d) 1.0 T, $484 \times 484 \text{ nm}^2$. In panel (a) the triangulation is represented by the dashed lines. The lattice deformation in panel (b) and the defects appearing in panel (d) are indicated.

defects. For higher fields, up to 1.0 T, we always obtained images without any defects, although the lattice as a whole may show deformations, visible in the data at $B = 0.3 \text{ T}$ [Fig. 3(b)]. Since the fast-scan direction is horizontal, this deformation is a real property of the lattice rather than an artifact of the measurement. We also observe rotations of the VL after changing the magnetic field and measuring again at the same spot: panels (a) and (b) of Fig. 3 are subsequently measured on the same location on the film. We propose that these observations are due to the presence of large domains of different orientation that change in size and orientation after a field step. This emphasizes once more the collective nature of the forces in VLs of amorphous superconductors, due to the weak random nature of the pinning.

For the 1.0 T data, we used a convolution filter with a kernel of size a_0^2 , since at these magnetic fields, the contrast becomes poor due to the overall suppression of the superconducting gap. Before measuring these images, we waited for 1.5 h to let the VL relax after the field was set to 1.0 T. Subsequently, we acquired 10 consecutive images on the same location of the film, each having an acquisition time of around 90 min. From this set of images, two subsequent images showed a lattice without defects, while all the others showed one or more defects on different locations in the lattice. Images without and with a defect are shown in Figs.

3(c) and 3(d). These apparently quite mobile defects indicate spontaneous nucleation of defects, which may be the first signal of the onset of melting at higher fields.¹⁴

To summarize, we have developed a technique which makes imaging vortex configurations in superconducting thin films possible in magnetic fields that were not accessible before. We applied the technique to films of $a\text{-Mo}_{2.7}\text{Ge}$ and NbN, resulting in clear images of their vortex configurations. Measurements on $a\text{-Mo}_{2.7}\text{Ge}$, a weak pinning material, show a triangular vortex lattice with defects appearing around 1.0 T. For NbN, a strong pinning material, the lattice is fully disordered. The technique can, in principle, be used to observe vortex configurations in any type-II superconductor on which Au can be grown in a smooth layer (possibly with the help of $a\text{-Mo}_{2.7}\text{Ge}$). This opens a way to study the microscopic behavior of the vortices, for example, at phase transitions, and can produce information on artificially structured samples.

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